



MMST4124

NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features

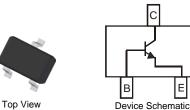
- **Epitaxial Planar Die Construction**
- Complementary PNP Type Available (MMST4126)
- Ideal for Medium Power Amplification and Switching
- Ultra-Small Surface Mount Package
- Lead Free/RoHS Compliant (Note 2)
- "Green" Device (Notes 3 and 4)

Mechanical Data

- Case: SOT-323
- Case Material: Molded Plastic, "Green" Molding Compound, Note 4. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- **Terminal Connections: See Diagram**
- Terminals: Matte Tin Finish annealed over Alloy 42 leadframe (Lead Free Plating) Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 3
- Ordering Information: See Page 3

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Weight: 0.006 grams (approximate)



Maximum Ratings @T_A = 25°C unless otherwise specified

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Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	30	V
Collector-Emitter Voltage	V _{CEO}	25	V
Emitter-Base Voltage	V _{EBO}	5.0	V
Collector Current - Continuous (Note 1)	lc	200	mA

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 1)	PD	200	mW
Thermal Resistance, Junction to Ambient (Note 1)	R _θ JA	625	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 5)			•		
Collector-Base Breakdown Voltage	V _{(BR)CBO}	30	_	V	$I_{C} = 10 \mu A, I_{E} = 0$
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}		_	V	$I_{\rm C} = 1.0 {\rm mA}, I_{\rm B} = 0$
Emitter-Base Breakdown Voltage	V _{(BR)EBO}		_	V	$I_{E} = 10 \mu A, I_{C} = 0$
Collector Cutoff Current	I _{CBO}	_	50	nA	$V_{CB} = 20V, I_E = 0V$
Emitter Cutoff Current	I _{EBO}	_	50	nA	$V_{EB} = 3.0V, I_{C} = 0V$
ON CHARACTERISTICS (Note 5)					
DC Current Gain	h _{FE}	120	360		I _C = 2.0mA, V _{CE} = 1.0V
		60	—		$I_{C} = 50 \text{mA}, V_{CE} = 1.0 \text{V}$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	0.30	V	$I_{C} = 50 \text{mA}, I_{B} = 5.0 \text{mA}$
Base-Emitter Saturation Voltage	V _{BE(SAT)}	_	0.95	V	$I_{\rm C} = 50 {\rm mA}, I_{\rm B} = 5.0 {\rm mA}$
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	Cobo	_	4.0	pF	$V_{CB} = 5.0V, f = 1.0MHz, I_E = 0$
Input Capacitance	Cibo	_	8.0	pF	$V_{EB} = 0.5V, f = 1.0MHz, I_{C} = 0$
Small Signal Current Gain	h _{fe}	120	480	_	V _{CE} = 1.0V, I _C = 2.0mA, f = 1.0kHz
Current Gain-Bandwidth Product	f⊤	300	_	MHz	V _{CE} = 20V, I _C = 10mA, f = 100MHz

Notes: 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

2. No purposefully added lead.

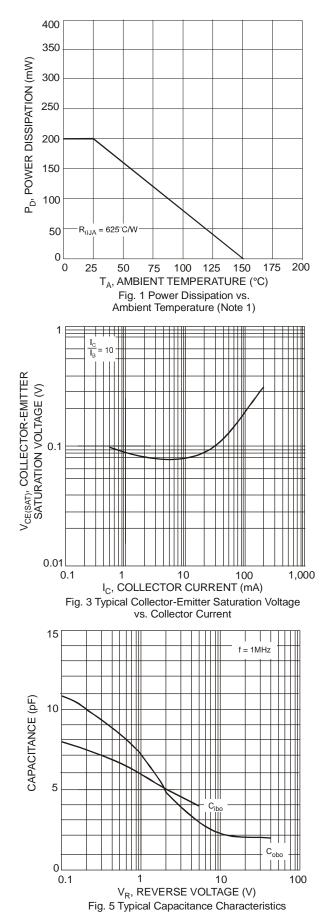
3. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.

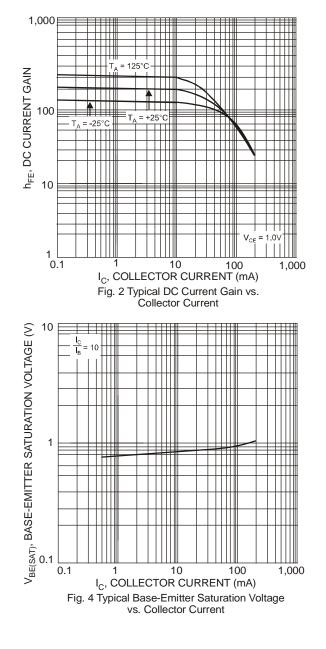
Product manufactured with Date Code 0627 (week 27, 2006) and newer are built with Green Molding Compound. Product manufactured prior to Date 4. Code 0627 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.

5. Short duration pulse test used to minimize self-heating effect.









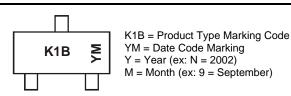


Ordering Information (Notes 4 and 6)

Part Number	Case	Packaging
MMST4124-7-F	SOT-323	3000/Tape & Reel

Notes: 6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

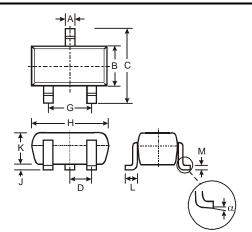
Marking Information



Date Code Key

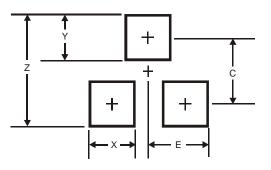
Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012	2013	2014	2015
Code	J	Κ	L	Μ	Ν	Р	R	s	Т	U	V	W	Х	Y	Z	Α	В	С
Month	Jan		Feb	Mai		Apr	May		Jun	Ju		Aug	Sep		Oct	Nov		Dec
WOIIII	Jaii		ren	IVIAI		Арі	Ivia	/	Juli	Ju		Aug	Sep			NUV		Dec
Code	1		2	3		4	5		6	7		8	9		0	N		D

Package Outline Dimensions



SOT-323						
Dim	Min	Max	Тур			
Α	0.25	0.40	0.30			
В	1.15	1.35	1.30			
С	2.00	2.20	2.10			
D	-	-	0.65			
G	1.20	1.40	1.30			
Н	1.80	2.20	2.15			
J	0.0	0.10	0.05			
κ	0.90	1.00	1.00			
L	0.25	0.40	0.30			
М	0.10	0.18	0.11			
α 0° 8° -						
All	Dimens	ions in	mm			

Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.8
Х	0.7
Y	0.9
С	1.9
E	1.0

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